



Mini-Circuits

ULTRA LOW NOISE, HIGH IP3

# Monolithic Amplifier **CMA-162LN+**

50Ω 0.7 to 1.6 GHz

## THE BIG DEAL

- Ceramic, Hermetic, Nitrogen Filled
- Low Noise Figure, 0.5 dB at 1 GHz
- High IP3, +30 dBm Typ. at 1 GHz
- Adjustable Gain, 19.7-23.5 dB at 1 GHz
- High P1dB, +20 dBm Typ. at 1 GHz
- Class 1B HBM ESD Rating (+500 V)
- Small Size, 3x3x1.14 mm
- No External Matching Components Required



Generic photo used for illustration purposes only

CASE STYLE: DL1721

**+RoHS Compliant**

The +Suffix identifies RoHS Compliance.  
See our website for methodologies and qualifications

MIL SCREENING AVAILABLE  
PLEASE CONSULT APPLICATIONS DEPT.

## APPLICATIONS

- Base Station Infrastructure
- Portable Wireless
- LTE
- GPS
- GSM
- Airborne Radar

## PRODUCT OVERVIEW

Mini-Circuits CMA-162LN+ is a E-pHEMT based Ultra-Low Noise MMIC Amplifier with a unique combinations of low noise and high IP3 making this amplifier ideal for sensitive high dynamic range receiver applications. This design operates on a single +4 V supply. The MMIC amplifier is bonded to a multilayer integrated LTCC substrate and then hermetically sealed under a controlled nitrogen atmosphere with gold-plated covers and eutectic AuSn solder. These amplifiers are capable of meeting MIL requirements for gross leak, fine leak, thermal shock, vibration, acceleration, mechanical shock, and HTOL. The testing can be done if requested.

## KEY FEATURES

Feature	Advantages
Ultra Low Noise, 0.5 dB at 1.0 GHz	Outstanding world class noise figure performance.
High IP3, +30 dBm at 1.0 GHz	Combining Low Noise and High IP3 makes this MMIC amplifier ideal for use in Low Noise Receiver Front End (RFE) as it gives the user advantages at both ends of the dynamic range: sensitivity & two-tone IM performance.
Adjustable Gain	By changing feedback resistor R1, gain can be changed from 19.7 to 23.5 dB at 1GHz
Ceramic Hermetic Package	Low inductance, repeatable performance, excellent reliability
Max Input Power, +25 dBm	Ruggedized design operates up to high input powers often seen at Receiver inputs eliminating the need for an external resistor.
High Reliability	Low, small signal operating current of 55 mA nominal maintains junction temperatures typically below +100°C at +85°C ground lead temperature.
Class 1B ESD (+500 V HBM)	The CMA-162LN+ is a super low noise pHEMT based design. Mini-Circuits incorporates ESD protection on die to achieve industry leading ESD performance for a low noise amplifier.

REV. D  
ECO-025417  
CMA-162LN+  
MCL NY  
250502

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ELECTRICAL SPECIFICATIONS<sup>1,2</sup> AT +25°C AND +4 V, UNLESS NOTED OTHERWISE

Parameter	Condition (GHz)	R1=267Ω <sup>1</sup>			R1=93Ω <sup>2</sup>			Units
		Min.	Typ.	Max.	Min.	Typ.	Max.	
Frequency Range		0.7		1.6	0.7		1.6	GHz
Noise Figure	0.7		0.62			0.62		dB
	0.8		0.53			0.50		
	1.0		0.49			0.44		
	1.3		0.55			0.59		
	1.6		0.76			0.70		
Gain	0.7		25.2			23.4		dB
	0.8		24.7			22.8		
	1.0	20.9	23.2	24.5		21.4		
	1.3		21.0			19.7		
	1.6		19.1			18.2		
Input Return Loss	0.7		13.9			14.9		dB
	0.8		24.0			28.4		
	1.0		15.0			17.3		
	1.3		11.0			12.6		
	1.6		9.7			10.9		
Output Return Loss	0.7		14.2			23.1		dB
	0.8		16.8			19.3		
	1.0		19.8			18.2		
	1.3		15.0			15.5		
	1.6		9.8			11.1		
Output Power @ 1 dB Compression <sup>3</sup>	0.7		+19.5			+18.3		dBm
	0.8		+19.8			+18.9		
	1.0		+19.9			+19.7		
	1.3		+19.7			+19.8		
	1.6		+18.8			+19.0		
Output IP3	0.7		+29.1			+28.3		dBm
	0.8		+30.3			+29.5		
	1.0		+30.3			+29.0		
	1.3		+30.1			+29.2		
	1.6		+29.4			+28.5		
Device Operating Voltage		+3.8	+4.0	+4.2	+3.8	+4.0	+4.2	V
Device Operating Current at +4 V			55	60		55	60	mA
DC Current Variation vs. Temperature at +4 V <sup>4</sup>			2			2		µA/°C
DC Current Variation vs. Voltage at +25°C			0.016			0.016		mA/mV
Thermal Resistance			53			53		°C/W

1. Measured on Mini-Circuits Characterization test board TB-756+. See Characterization Test Circuit (Fig. 1) R1=267Ω.

2. Measured on Mini-Circuits Characterization test board TB-756+. See Characterization Test Circuit (Fig. 1) R1=93Ω.

3. Current increases at P1dB.

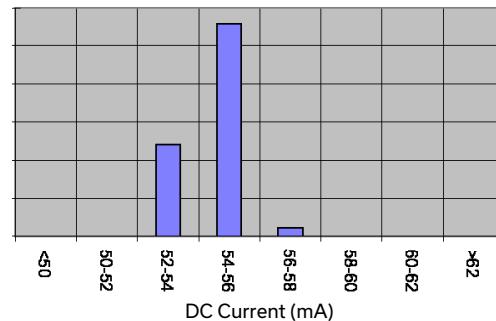
4. (Current at +85°C - Current at -45°C)/130

## ABSOLUTE MAXIMUM RATINGS

Parameter	Ratings
Operating Temperature (Ground Lead)	-55°C to +105°C
Storage Temperature	-65°C to +125°C
Junction Temperature	+150°C
Total Power Dissipation	0.55 W
Input Power (CW), $V_d=+4$ V	+25 dBm
DC Voltage	+5.5 V

Permanent damage may occur if any of these limits are exceeded. These ratings are not intended for continuous normal operation.

## DC CURRENT HISTOGRAM

**Mini-Circuits®**

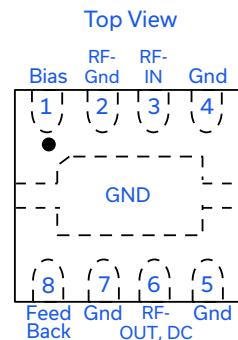
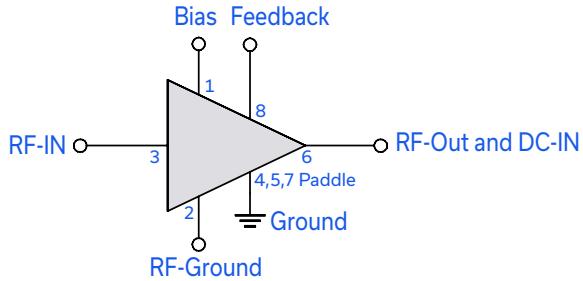


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## SIMPLIFIED SCHEMATIC AND PAD DESCRIPTION



Function	Pin Number	Description
RF-IN	3	Connects to RF input via C1 and Pad 2 via L1
RF-OUT, DC	6	Connects to RF out via C2, Pad 8 via R1, and C3
RF-Ground	2	Connects to ground via C4 and Pad 3 via L1
Bias	1	Connects to Supply voltage ( $V_s$ ) via Rbias
Feedback	8	Connected to pads 6, 1 via R1 and C3
Ground	4,5,7 & Paddle	Connects to ground



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## RECOMMENDED APPLICATION AND CHARACTERIZATION TEST CIRCUIT

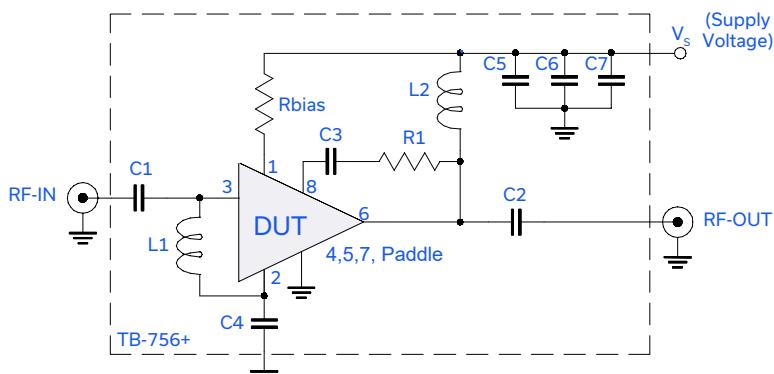


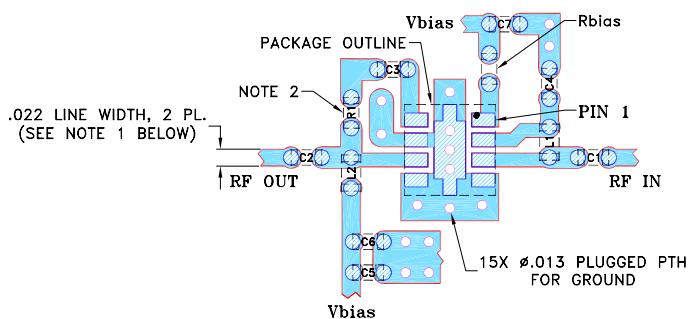
Fig 1. Application and Characterization circuit

Note: This block diagram is used for characterization. (DUT soldered on Mini-Circuits Characterization test board TB-756+) Gain, Return Loss, Output Power at 1 dB Compression (P1dB), Output IP3 (OIP3) and Noise Figure measured using Agilent's N5242A PNA-X microwave network analyzer.

## Conditions:

1. Gain and Return Loss:  $P_{IN} = -25$  dBm
2. Output IP3 (OIP3): Two tones, spaced 1 MHz apart, 0 dBm/tone at output.

## SUGGESTED PCB LAYOUT (PL-404)

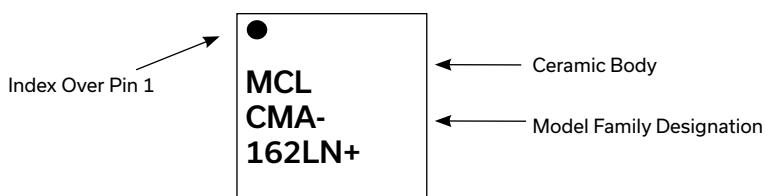


NOTES: 1. TRACE WIDTH IS SHOWN FOR ROGERS RO4350B WITH DIELECTRIC THICKNESS .010"  $\pm$  .001"; COPPER: 1/2 OZ. EACH SIDE. FOR OTHER MATERIALS TRACE WIDTH MAY NEED TO BE MODIFIED. 2. 0402 SIZE CHIP FOOT PRINTS SHOWN FOR REFERENCE, FOR COMPONENT VALUE REFER TO TB-756+. 3. BOTTOM SIDE OF THE PCB IS CONTINUOUS GROUND PLANE.

DENOTES PCB COPPER LAYOUT WITH SMOBC (SOLDER MASK OVER BARE COPPER)

DENOTES COPPER LAND PATTERN FREE OF SOLDER MASK

## PRODUCT MARKING



Markings in addition to model number designation may appear for internal quality control purposes.



ULTRA LOW NOISE, HIGH IP3

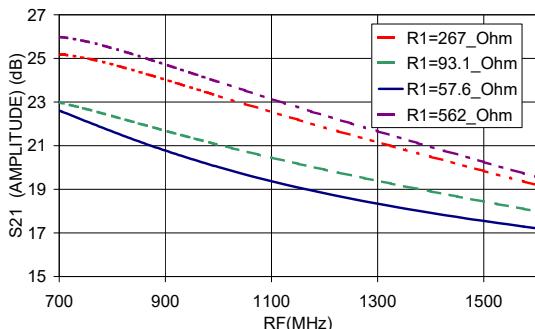
# Monolithic Amplifier **CMA-162LN+**

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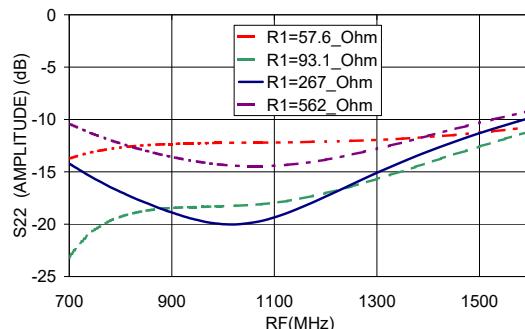
50Ω 0.7 to 1.6 GHz

## ADJUSTABLE GAIN PERFORMANCE (VS. R1)

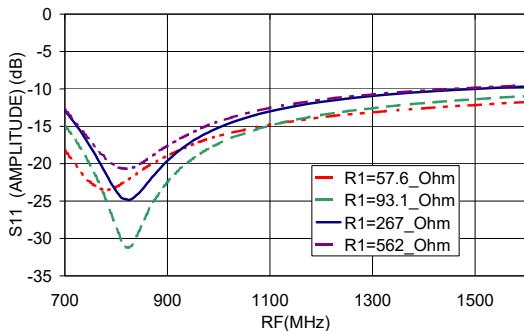
S21 (AMPLITUDE,dB) Vs. Frequency and R1 Values



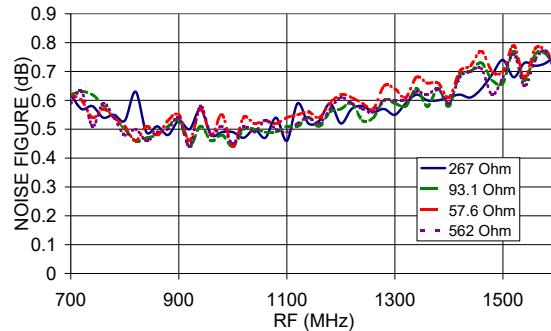
S22 (AMPLITUDE,dB) Vs. Frequency and R1 Values



S11 (AMPLITUDE,dB) Vs. Frequency and R1 Values



NOISE FIGURE (dB) vs. Frequency and R1 Values





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**ADDITIONAL DETAILED TECHNICAL INFORMATION IS AVAILABLE ON OUR DASHBOARD. [CLICK HERE](#)**

Performance Data & Graphs	Table Graphs S-Parameter (S2P Files) Data Set (.zip file)
Case Style	DL1721 Ceramic package, exposed paddle, Terminal Finish: Ni,Pd,Au
Tape & Reel Standard Quantities Available on Reel	F66-1 7" Reels with 20, 50, 100, 200, 500, 1000 & 2000 devices
Suggested Layout for PCB Design	PL-404
Evaluation Board	TB-756+
Environmental Ratings	ENV68

**ESD RATING**

Human Body Model (HBM): Class 1B (500 to < 1000 V) in accordance with ANSI/ESD STM 5.1 - 2001  
 Machine Model (MM): Class M1 (pass 25 V) in accordance with ANSI/ESD STM5.2-1999

**MSL RATING**

Moisture Sensitivity: MSL1 (these parts are hermetic, air cavity and therefore, MSL ratings do not strictly apply. For handling purpose, use MSL1)

**QUALIFICATION TESTING**

The table below shows the initial qualification testing performed. If required, parts can be subjected to 100% screening and qualifications testing per MIL standard requirement.

Test Description		Test Method/Process	Results
1	Hermeticity (fine and gross leak)	MIL-STD-202 Method 112, Cond. C & D	Pass
2	Acceleration, 30Kg, Y1 Direction	MIL-STD-883 Method 2001 Cond. E	Pass
3	Vibration , 10-2000Hz sine, 20g, 3 axis	MIL-STD-202 Method 204, Cond. D	Pass
4	Mechanical shock	MIL-STD-202 Method 213, Cond . A	Pass
5	PIND 20G's @130 Hz	MIL-STD-750 Method 2052.2	Pass
6	Temp Cycle -55C/+125C, 1000 Cycles	MIL-STD-202 Method 107	Pass
7	Autoclave, 121C, RH 100%, 15 Psig, 96 hrs	JESD22-A102C	Pass
8	HTOL, 1000hrs, 105C at rated Voltage condition	MIL-STD-202 Method 108, Cond . D	Pass
9	Bend Test	JESD22-B113	Pass
10	Resistance to soldering heat, 3x reflow, 260C peak	JESD22-B102	Pass
11	Drop Test	JESD22-B111	Pass
12	Adhesion Strength	Push Test>10 lb	Pass

**NOTES**

- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
- B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuits' applicable established test performance criteria and measurement instructions.
- C. The parts covered by this specification document are subject to Mini-Circuits' standard limited warranty and terms and conditions (collectively, "Standard Terms"); Purchasers of this part are entitled to the rights and benefits contained therein. For a full statement of the standard terms and the exclusive rights and remedies thereunder, please visit Mini-Circuits' website at [www.minicircuits.com/terms/viewterm.html](http://www.minicircuits.com/terms/viewterm.html)